- Designed for Complementary Use with the BD544 Series
- 70 W at 25°C Case Temperature
- 8 A Continuous Collector Current
- 10 A Peak Collector Current
- Customer-Specified Selections Available

TO-220 PACKAGE

Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING			VALUE	UNIT
	BD543 BD543A		40	
Collector-base voltage (I _E = 0)			60	V
Collector-base voltage (IE = 0)	BD543B	V _{CBO}	80	v
	BD543C		100	
	BD543		40	
Collector-emitter voltage (I _B = 0)	BD543A	V	60	V
Collector-entitler voltage (IB = 0)	BD543B	V _{CEO}	80	V
	BD543C		100	
Emitter-base voltage		V _{EBO}	5	V
Continuous collector current		I _C	8	Α
Peak collector current (see Note 1)		I _{CM}	10	Α
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			70	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			2	W
Operating free air temperature range			-65 to +150	°C
Operating junction temperature range			-65 to +150	°C
Storage temperature range	T _{stg}	-65 to +150	°C	
Lead temperature 3.2 mm from case for 10 seconds			260	°C

NOTES: 1. This value applies for $t_p \leq 0.3$ ms, duty cycle $\leq 10\%.$

- 2. Derate linearly to 150°C case temperature at the rate of 0.56 W/°C.
- 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

PRODUCT INFORMATION

Information is current as of publication date. Products conform to specifications in accordance with the terms of Power Innovations standard warranty. Production processing does not necessarily include testing of all parameters.



BD543, BD543A, BD543B, BD543C NPN SILICON POWER TRANSISTORS

JUNE 1973 - REVISED MARCH 1997

electrical characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C = 30 mA	I _B = 0	BD543 BD543A	40 60			V
(BIT) DE O		(see Note 4)		BD543B BD543C	80 100			
I _{CES}	Collector-emitter cut-off current	$V_{CE} = 40 \text{ V}$ $V_{CE} = 60 \text{ V}$ $V_{CE} = 80 \text{ V}$ $V_{CE} = 100 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	BD543 BD543A BD543B BD543C			0.4 0.4 0.4 0.4	mA
I _{CEO}	Collector cut-off current	V _{CE} = 30 V V _{CE} = 60 V	$I_{B} = 0$ $I_{B} = 0$	BD543/543A BD543B/543C			0.7 0.7	mA
I _{EBO}	Emitter cut-off current	V _{EB} = 5 V	I _C = 0				1	mA
h _{FE}	Forward current transfer ratio	$V_{CE} = 4 V$ $V_{CE} = 4 V$ $V_{CE} = 4 V$	$I_C = 1 A$ $I_C = 3 A$ $I_C = 5 A$	(see Notes 4 and 5)	60 40 15			
V _{CE(sat)}	Collector-emitter saturation voltage	$I_B = 0.3 \text{ A}$ $I_B = 1 \text{ A}$ $I_B = 1.6 \text{ A}$	$I_C = 3 A$ $I_C = 5 A$ $I_C = 8 A$	(see Notes 4 and 5)			0.5 0.5 1	V
V _{BE}	Base-emitter voltage	V _{CE} = 4 V	I _C = 5 A	(see Notes 4 and 5)			1.4	V
h _{fe}	Small signal forward current transfer ratio	V _{CE} = 10 V	I _C = 0.5 A	f = 1 kHz	20			
h _{fe}	Small signal forward current transfer ratio	V _{CE} = 10 V	I _C = 0.5 A	f = 1 MHz	3			

NOTES: 4. These parameters must be measured using pulse techniques, t_p = 300 μs , duty cycle \leq 2%.

thermal characteristics

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.79	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

resistive-load-switching characteristics at 25°C case temperature

	PARAMETER TEST CONDITIONS †		MIN	TYP	MAX	UNIT		
t _{on}	Turn-on time	I _C = 6 A	$I_{B(on)} = 0.6 A$	$I_{B(off)} = -0.6 A$		0.6		μs
t _{off}	Turn-off time	$V_{BE(off)} = -4 V$	$R_L = 5 \Omega$	t_p = 20 μ s, dc \leq 2%		1		μs

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

^{5.} These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN VS COLLECTOR CURRENT TCS633AI TCS63AI TCS6AI T

Figure 1.

COLLECTOR-EMITTER SATURATION VOLTAGE

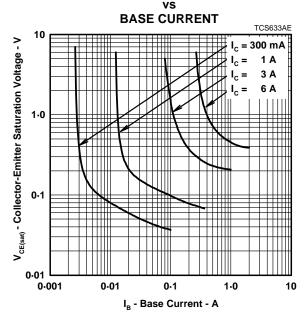
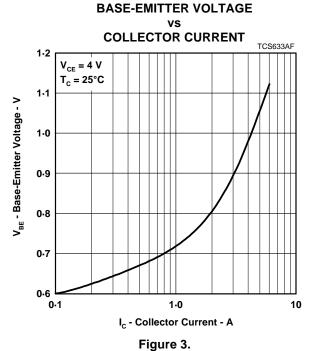
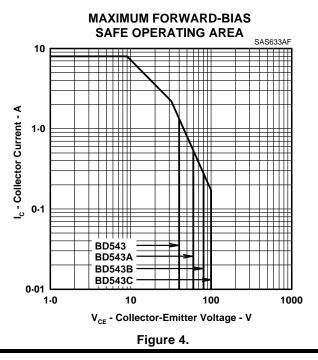


Figure 2.



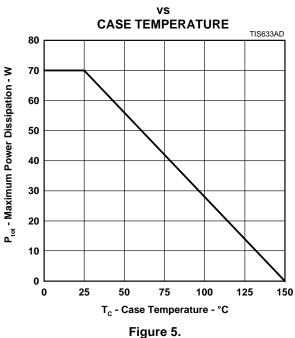


MAXIMUM SAFE OPERATING REGIONS



THERMAL INFORMATION

MAXIMUM POWER DISSIPATION

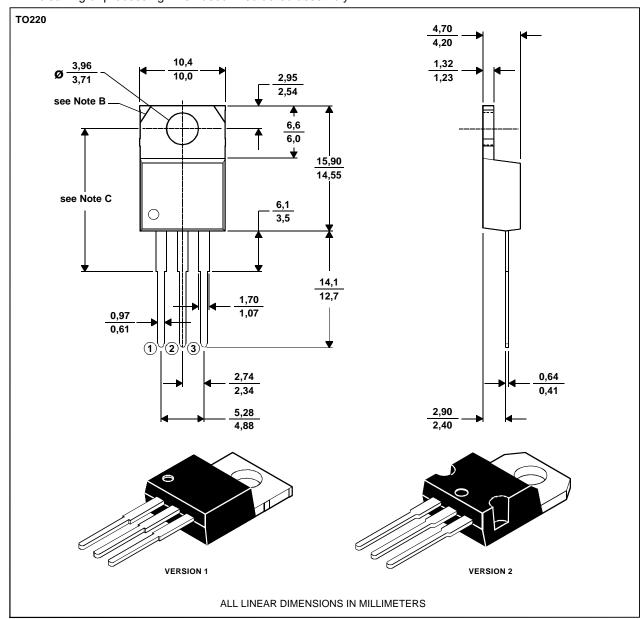


MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. The centre pin is in electrical contact with the mounting tab.

- B. Mounting tab corner profile according to package version.
- C. Typical fixing hole centre stand off height according to package version. Version 1, 18.0 mm. Version 2, 17.6 mm.

MDXXBE





BD543, BD543A, BD543B, BD543C NPN SILICON POWER TRANSISTORS

JUNE 1973 - REVISED MARCH 1997

IMPORTANT NOTICE

Power Innovations Limited (PI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to verify, before placing orders, that the information being relied on is current.

PI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with PI's standard warranty. Testing and other quality control techniques are utilized to the extent PI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except as mandated by government requirements.

PI accepts no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor is any license, either express or implied, granted under any patent right, copyright, design right, or other intellectual property right of PI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.

PI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS.

Copyright © 1997, Power Innovations Limited